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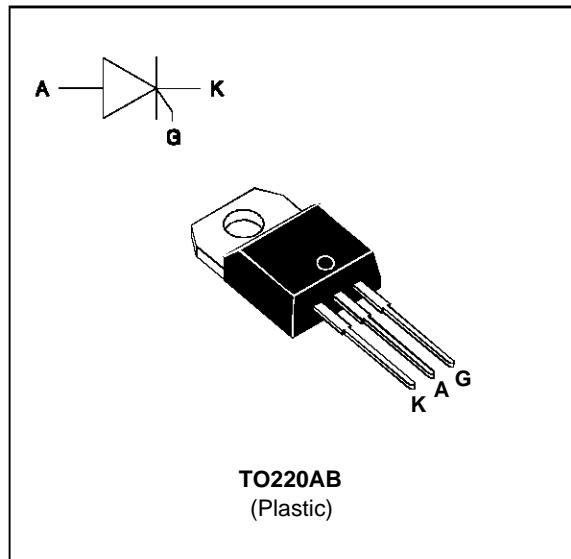
FEATURES

- HIGH SURGE CAPABILITY
- HIGH ON-STATE CURRENT
- HIGH STABILITY AND RELIABILITY

DESCRIPTION

The TYN 204 ---> TYN 1004 Family of Silicon Controlled Rectifiers uses a high performance glass passivated technology.

This general purpose Family of Silicon Controlled Rectifiers is designed for power supplies up to 400Hz on resistive or inductive load.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
I _T (RMS)	RMS on-state current (180° conduction angle)	4	A
I _T (AV)	Average on-state current (180° conduction angle, single phase circuit)	2.5	A
I _{TSM}	Non repetitive surge peak on-state current (T _j initial = 25°C)	tp = 8.3 ms	A
		tp = 10 ms	
I ² t	I ² t value	18	A ² s
dl/dt	Critical rate of rise of on-state current Gate supply : I _G = 100 mA dI _G /dt = 1 A/μs	100	A/μs
T _{stg} T _j	Storage and operating junction temperature range	- 40 to + 150 - 40 to + 125	°C °C
T _I	Maximum lead temperature for soldering during 10 s at 4.5 mm from case	260	°C

Symbol	Parameter	TYN					Unit
		204	404	604	804	1004	
V _{DRM} V _{RRM}	Repetitive peak off-state voltage T _j = 125 °C	200	400	600	800	1000	V

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th} (j-a)	Junction to ambient	60	°C/W
R _{th} (j-c) DC	Junction to case for DC	2.5	°C/W

GATE CHARACTERISTICS (maximum values)

P_G (AV) = 1W P_{GM} = 10W (tp = 20 μs) I_{FGM} = 4A (tp = 20 μs) V_{RGM} = 5 V.

ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions			Value	Unit
I _{GT}	V _D =12V (DC) R _L =33Ω	T _j =25°C	MAX	15	mA
V _{GT}	V _D =12V (DC) R _L =33Ω	T _j =25°C	MAX	1.5	V
V _{GD}	V _D =V _{DRM} R _L =3.3kΩ	T _j = 110°C	MIN	0.2	V
t _{gt}	V _D =V _{DRM} I _G = 40mA dI _G /dt = 0.5A/μs	T _j =25°C	TYP	2	μs
I _L	I _G = 1.2 I _{GT}	T _j =25°C	TYP	50	mA
I _H	I _T = 100mA gate open	T _j =25°C	MAX	30	mA
V _{TM}	I _{TM} = 8A tp= 380μs	T _j =25°C	MAX	1.8	V
I _{DRM} I _{RRM}	V _{DRM} Rated V _{RRM} Rated	T _j =25°C T _j = 110°C	MAX	0.01 2	mA
dV/dt	Linear slope up to V _D =67%V _{DRM} gate open	T _j = 110°C	MIN	200	V/μs
t _q	V _D =67%V _{DRM} I _{TM} = 8A V _R = 25V dI _{TM} /dt=30 A/μs dV _D /dt= 50V/μs	T _j = 110°C	TYP	70	μs

Fig.1 : Maximum average power dissipation versus average on-state current.

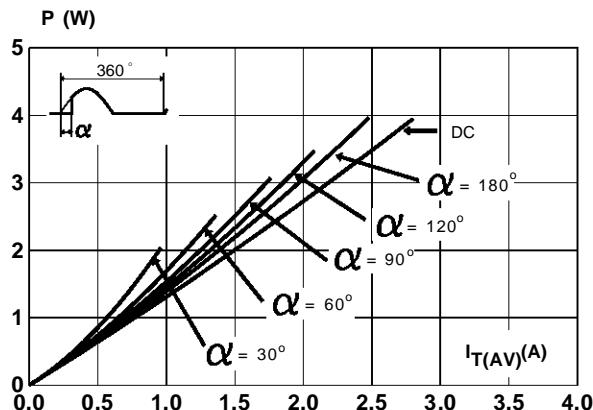


Fig.3 : Average on-state current versus case temperature.

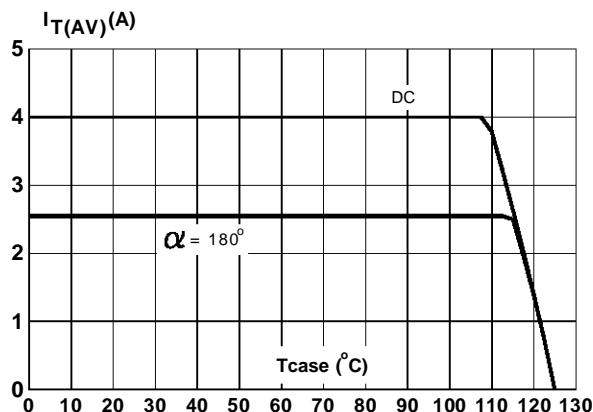


Fig.5 : Relative variation of gate trigger current versus junction temperature.

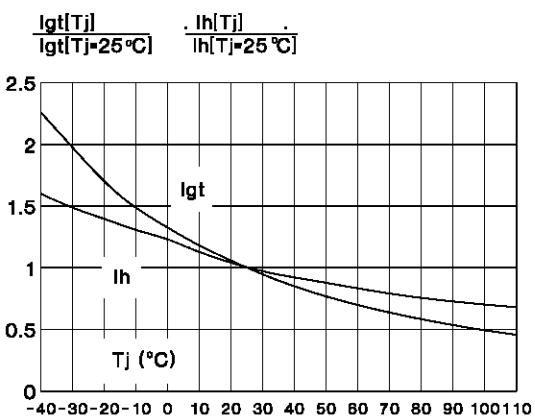


Fig.2 : Correlation between maximum average power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact.

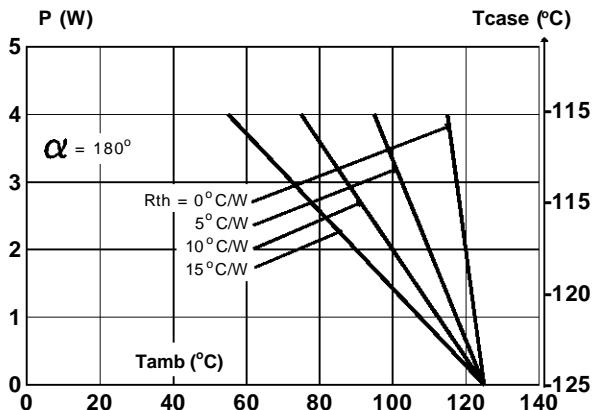


Fig.4 : Relativa variation of thermal impedance versus pulse duration.

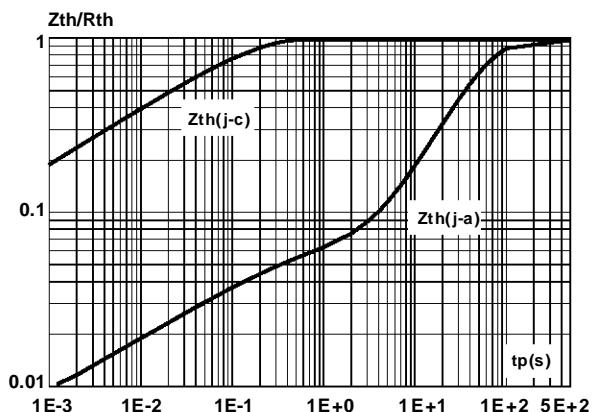
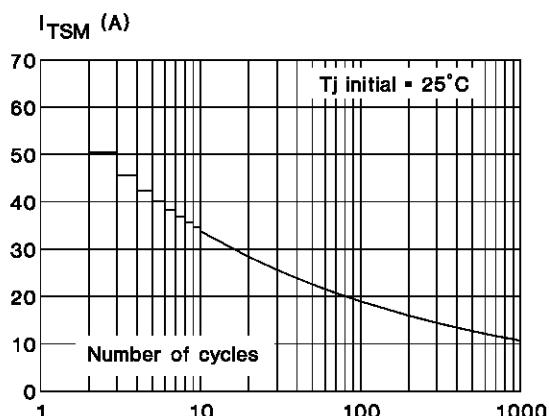


Fig.6 : Non repetitive surge peak on-state current versus number of cycles.



TYN 204 ---> TYN 1004

Fig.7 : Non repetitive surge peak on-state current for a sinusoidal pulse with width : $t \leq 10$ ms, and corresponding value of I^2t .

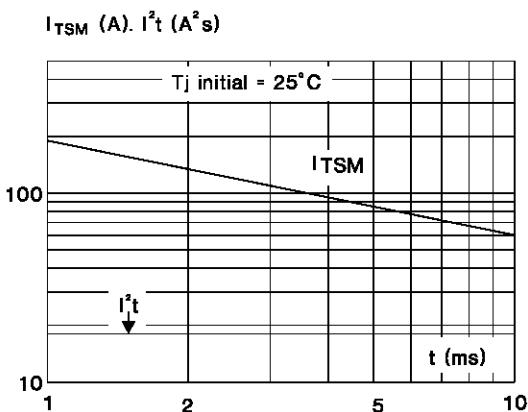
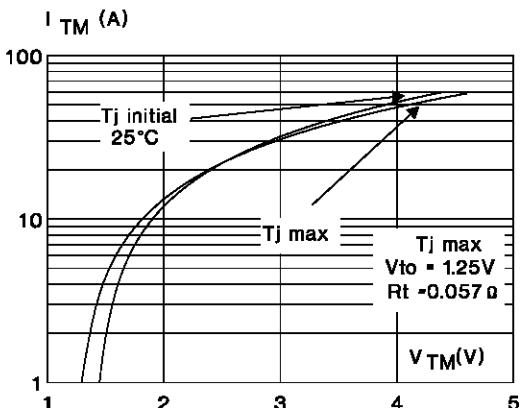
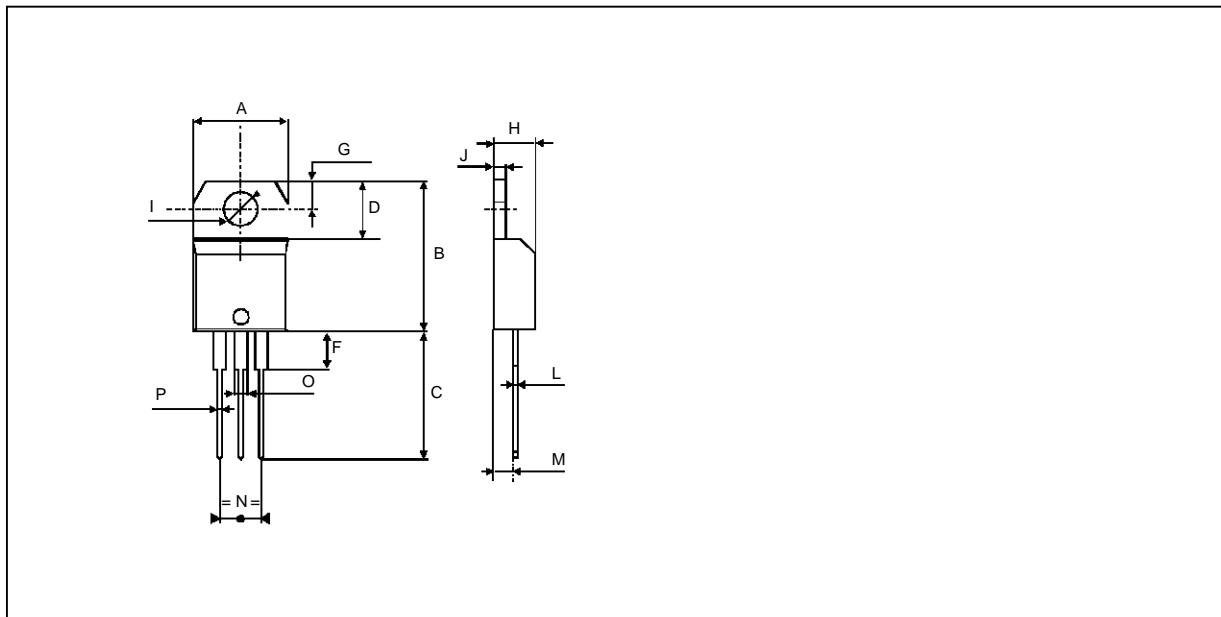


Fig.8 : On-state characteristics (maximum values).



PACKAGE MECHANICAL DATA

TO220AB Plastic



Cooling method : C

Marking : type number

Weight : 2.3 g

Recommended torque value : 0.8 m.N.

Maximum torque value : 1 m.N.

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